
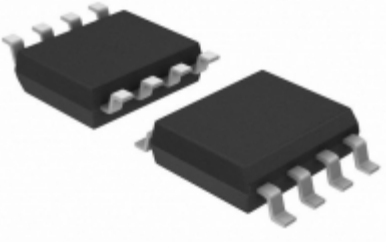
	<p>SI4368DY-T1-E3</p>
	<p>Hersteller-Teilenummer: SI4368DY-T1-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 17A 8-SOIC</p> <p>Datenblätter:  SI4368DY-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 31284 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI4368DY-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 30V 17A 8-SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	31284 pcs Stock
detaillierte Beschreibung	N-Channel 30V 17A (Ta) 1.6W (Ta) Surface Mount 8-
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Verlustleistung (max)	1.6W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	17A (Ta)
Rds On (Max) @ Id, Vgs	3.2 mOhm @ 25A, 10V
VGS (th) (Max) @ Id	1.8V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	80nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	8340pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI4368DY-T1-E3TR

SI4368DY-T1-E3 ist neu im Original, Suche SI4368DY-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI4368DY-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI4368DY-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI4364DY-T1-E3 VISHAY SI4364DY-T1-E3 VISHAY</p>	 <p>SI4368DY VIS SI4368DY VIS</p>	 <p>SI4366DY-T1-E3 V SI4366DY-T1-E3 V</p>	 <p>SI4368DY-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 17A 8-SOIC</p>
 <p>SI4370DY-T1-E3 V SI4370DY-T1-E3 V</p>	 <p>SI4364DY-T1 VISHAY SI4364DY-T1 VISHAY</p>	 <p>SI4376DY-T1-E3 V SI4376DY-T1-E3 V</p>	 <p>SI4368DY-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 17A 8-SOIC</p>

heiße Teile

Mehr

SI4348DY	SI4348DY-T1-E3	SI4348DY-T1-E3	SI4348DY-T1-GE3	SI4354DY-T1-E3
SI4354DY-T1-E3	SI4355-B1A-FMR	SI4356ADY-T1-E3	SI4356DY	SI4356DY-T1
SI4356DY-T1-E3	SI4362BDY	SI4362BDY-T1-E3	SI4362BDY-T1-E3	SI4362BDY-T1-E3-PBF
SI4362DY	SI4362DY-T1	SI4362DY-T1-E3	SI4362DY-T1-E3.	SI4364DY
SI4364DY-T1	SI4364DY-T1-E3	SI4366DY-T1-E3	SI4368DY	SI4368DY-T1-E3
SI4370DY-T1-E3	SI4376DY-T1-E3	SI4378DY-T1	SI4378DY-T1-E3	SI4378DY-T1-E3
SI4382DY-T1-E3	SI4384DY	SI4384DY-T1-E3	SI4384DY-T1-E3	SI4384DY-T1-E3..
SI4386DY	SI4386DY-T1-E3	SI4386DY-T1-E3	SI4386DY-T1-GE3	SI4386DY-T1-GE3
SI4388DY	SI4388DY-T1-GE3	SI4388DY-T1-GE3	SI4390DY	SI4390DY-T1
SI4390DY-T1-E3	SI4390DY-T1-E3	SI4390DY-T1-E3	SI4392ADY	SI4392ADY-T1-E3

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